

# TRIGGER DIODES

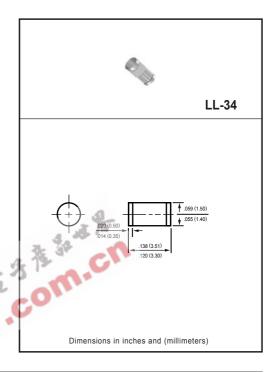
### **FEATURES**

- \* VBO: 32V/34V/40V VERSIONS
- \* Low Breakover Current

### **DESCRIPTION**

High reliability glass passivation insuring parameter stability and protection against junction contamination

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current.



### MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATING	SYMBOL	VALUE	UNITS
Repetitive Peak On-State Current tp=20uA,F=100Hz	I <sub>TRM</sub>	2	Α
Power Dissipation (@ T <sub>A</sub> =50°C)	Р	150	mW
Derate Above +50°C		4.0	mW/°C
Storage Temperature Range	T <sub>STG</sub>	-40 to + 125	°C
Junction Temperature	TJ	125	°C

## ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

RATING	SYMBOL	VALUE				LINUTO
		DB3S-1		DB3S-2		UNITS
Breakover Voltage(Forward and Reverse)	V <sub>BO</sub>	Min	Max	Min	Max	Volts
at IBO,C=22nF**		30	34	28	36	7 70113
Maximum Breakover Voltage Symmetry delta VBO= +VBO - -VBO  C=22nF	delta V <sub>BO</sub>	+/-2				
Minimum Dynamic Breakover Voltage delta I=IBO to IF=10mA (see Fig3)	delta V+/-	5				Volts
Minimum Output Voltage* (see Fig 2)	Vo	5				
Peak Breakover Current at Breakorver Voltage* C=22nF**	I <sub>BO</sub>	25 100			uA	
Rise Time* (see Fig3)	tr	1.5				uS
Leakage Current* V <sub>B</sub> =0.5V <sub>BO</sub> max (see Fig1)	IB	10				uA

NOTES: 1. \*Electrical characteristic applicable in both forward and reverse derections.

- 2.\*\*Connected in parallel with the devices.
- 3. "Fully ROHS compliant", "100% Sn plating (Pb-free)".

2007-1





